

# T495A475M010ATA4K5

T495 Auto, Tantalum, MnO2 Tantalum, Commercial Grade, 4.7 uF, 20%, 10 VDC, SMD, MnO2, Molded, Low ESR, Auto, AEC-Q200, 4.5 Ohms, 1.8 mm, 1206 / 3216



Click [here](#) for the 3D model.

## General Information

Series	T495 Auto
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, Low ESR, Auto, AEC-Q200
Features	Low ESR, Automotive
RoHS	Yes
Termination	Tin
Qualifications	AEC-Q200
Typical Component Weight	58.6 mg

Dimensions	
L	3.2mm +/-0.2mm
W	1.6mm +/-0.2mm
H	1.6mm +/-0.2mm
T	0.13mm REF
S	0.8mm +0.2/-0.3mm
F	1.2mm +/-0.1mm
A	1.2mm MIN
B	0.4mm +/-0.15mm
E	1.3mm REF
G	1.1mm REF
P	0.4mm REF
R	0.4mm REF
X	0.1mm +/-0.1mm REF

Specifications	
Capacitance	4.7 uF
Tolerance	20%
Voltage DC	10 VDC (85C), 6.7 VDC (125C)
Temperature Range	-55/+125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	N/A
ESR	4500 mOhms (100kHz 25C)
Ripple Current	129 mA (rms, 100kHz 25C), 116.1 mA (rms, 85C), 51.6 mA (rms, 125C)
Leakage Current	0.5 uA (5min 25°C)

Packaging Specifications	
Packaging	T&R, 178mm
Packaging Quantity	2000

Statements of suitability for certain applications are based on our knowledge of typical operating conditions for such applications, but are not intended to constitute - and we specifically disclaim - any warranty concerning suitability for a specific customer application or use. This Information is intended for use only by customers who have the requisite experience and capability to determine the correct products for their application. Any technical advice inferred from this Information or otherwise provided by us with reference to the use of our products is given gratis, and we assume no obligation or liability for the advice given or results obtained.